

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	653642	(light near emitting near (device or diode or element)) or LED or (laser near diode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/18 18:01
L2	1242	((light near transparent) or (light near permeable)) near (electrode or contact or conductor or conductive)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/18 18:02
L3	2824	(p-type near GaN) or p-GaN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/18 18:03
L4	2335206	resistance	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/18 18:03
L5	20	I1 and I2 and I3 and I4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/18 18:03